

Malavika A. Bhide 🔍, Joe A. Manzi, Caroline E. Knapp 🕒 and Claire J. Carmalt *🕩

Department of Chemistry, University College London, 20 Gordon Street, London WC1H 0AJ, UK; malavika.bhide.14@ucl.ac.uk (M.A.B.); j.manzi@alumni.ucl.ac.uk (J.A.M.); caroline.knapp@ucl.ac.uk (C.E.K.) * Correspondence: c.j.carmalt@ucl.ac.uk

Abstract: A set of heteroleptic ethyl zinc β -amidoenoates (**1**, **2**) and β -ketoiminates (**3**) of the form [LZnEt]₂ with varying steric bulk have been synthesised via the reaction of diethylzinc with β -aminoenoate ligands HL¹ and HL² and β -ketoimine HL³. These complexes have been characterised via ¹H and ¹³C NMR, mass spectrometry and single-crystal X-ray diffraction, which unambiguously determined all three structures as dimeric species in the solid state. We observe the unusual dimerisation of **1** and **2** through coordination of the central zinc atom to the methine carbon of the second monomer, which gives these complexes high reactivity. The thermal properties of complex **3** are explored via thermal gravimetric analysis (TGA), to investigate their potential as single-source precursors to zinc oxide, which shows that **3** has a significantly lower decomposition temperature as compared to its bis-ligated counterpart [Zn(L³)₂], which gives **3** promise as a single-source precursor to zinc oxide.

Keywords: precursor; dimerisation; materials; zinc oxide; chemical vapour deposition

1. Introduction

Zinc oxide (ZnO) is widely used as a transparent conducting oxide (TCO) material. TCOs combine high electrical conductivity with optical transparency, making them an essential and industrially important class of material. Although TCOs such as indium-doped tin oxide (ITO) and fluorine-doped tin oxide (FTO) are the most industrially produced for electronic applications, the scarcity and subsequent rising cost of indium requires a shift towards TCO materials incorporating more abundant elements, such as ZnO [1,2].

Deposition of ZnO thin films has been undertaken via several methods such as sputtering [3], pulsed vapour deposition [4], spray pyrolysis [5] and chemical vapour deposition (CVD) [6–8]. The advantage of using solution-based methods such as aerosol-assisted CVD is that precursors only have to be soluble, which therefore allows for a greater range of precursors to ZnO. Diethylzinc is the most widely used precursor to ZnO thin films via vapour deposition methods [9,10]. An in situ reaction with an oxygen source, commonly methanol, produces highly conductive ZnO films with excellent transparency. The drawback of using diethylzinc is its highly pyrophoric nature, making its use and handling difficult, especially for scale-up processes. A shift towards single-source precursors (SSPs) for ZnO thin films has led to several complexes being reported in the literature, including zinc acetate [11], zinc β-diketonates [12], zinc β-ketoiminates [13–15], zinc β-amidoenoates [16], zinc oxanes [17] and zinc alkoxides [18], to name a few. These complexes are mostly homoleptic bis-ligated species, and offer the advantage of stability and ease of handling. Although they are still air- and moisture-sensitive, they are relatively stable compared to pyrophoric diethylzinc. This however comes at a cost—the thermal decomposition temperatures of these complexes tend to be higher, as well as having greater carbon contamination in the resultant deposits upon decomposition [19,20].

In this work, we explore the synthesis of a set of heteroleptic ethyl zinc β -amidoenoates and β -ketoiminates with a view to using them as SSPs to ZnO. We hypothesise that the



Citation: Bhide, M.A.; Manzi, J.A.; Knapp, C.E.; Carmalt, C.J. Synthetic and Structural Studies of Ethyl Zinc β -Amidoenoates and β -Ketoiminates. *Molecules* **2021**, *26*, 3165. https:// doi.org/10.3390/molecules26113165

Academic Editor: Charles L. B. Macdonald

Received: 29 April 2021 Accepted: 20 May 2021 Published: 25 May 2021

Publisher's Note: MDPI stays neutral with regard to jurisdictional claims in published maps and institutional affiliations.



Copyright: © 2021 by the authors. Licensee MDPI, Basel, Switzerland. This article is an open access article distributed under the terms and conditions of the Creative Commons Attribution (CC BY) license (https:// creativecommons.org/licenses/by/ 4.0/).



2. Results and Discussion

The β -aminoenoates ligands MeC(NH^{*i*}Pr)CHC(O)OEt (HL¹) and MeC(NH(CH₂)₂^{*i*}Pr) CHC(O)OEt (HL²) were synthesised via 1:1 acid-catalysed condensation reactions between ethyl acetoacetate and isopropylamine and isopentylamine, respectively, using K-10 mont-morillonite clay as the acid catalyst. The ligands were afforded in excellent yields using this method. Following standard synthetic routes for the preparation of β -ketoimine ligands, MeC(NH^{*i*}Pr)CHC(O)Me (HL³) was synthesised via a simple 1:1 condensation reaction of acetylacetone and isopropylamine, and isolated as an orange oil of a high purity and with a good yield (Figure 1).

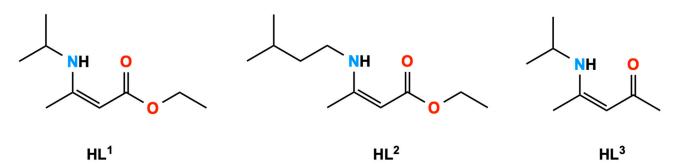


Figure 1. Ligands used in this work.

The ethyl zinc β -amidoenoate complexes **1** and **2**, and the ethyl zinc β -ketoiminate complex **3**, were synthesised via 1:1 reactions of diethylzinc with the respective β -aminoenoate or β -ketoimine in toluene. After reduction of the solvent in vacuo, all three compounds crystallised out of concentrated toluene solutions after being stored at -18 °C for 24 h (**3**) and 48 h (**1**, **2**). Compounds **1**, **2** and **3** were all characterised by ¹H and ¹³C NMR spectroscopy, as well as single-crystal X-ray diffraction (XRD), which confirmed the structures as dimeric species in the solid state (Figure 2). Peaks observed for the β -amidoenoate protons in the ¹H NMR spectrum of **1** and **2** were all shifted as compared to the free ligands, confirming coordination to the zinc centre, and we also saw triplet–quartet peaks corresponding to the bound ethyl groups appearing as broad signals.

The ethylzinc β -amidoenoates **1** and **2** both crystallised out as centrosymmetric crystals in the triclinic space group $P\overline{1}$, each with two zinc centres; one of which was unique and one of which was symmetrically generated about an inversion centre. Both the complexes dimerise analogously, with dative interactions between the zinc atom on one monomeric unit and the methine carbon on the ligand of the second monomeric unit (Figure 3). This dimerisation is uncommon in zinc alkyl complexes, with most dimerisation occurring through a [Zn–L]₂ (L = donor atom) ring interaction (Figure 3, left) [21–24]. A bis (Nheterocyclic carbene) zinc ethyl complex previously reported dimerises in a similar fashion to **1** and **2**, though this was due to the unusual deprotonation of the methylene proton of the ligand backbone by diethylzinc, and the formation of a formal Zn–C bond (Figure 3, right) [25].

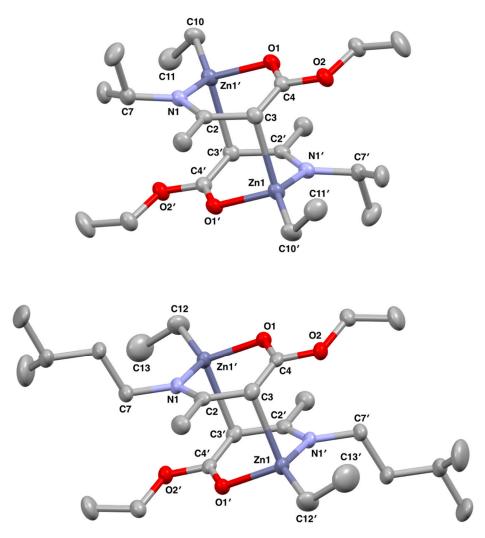


Figure 2. Solid state structures of **1** (**above**) and **2** (**below**) with thermal ellipsoids drawn at 50% probability and with hydrogen atoms omitted for clarity.

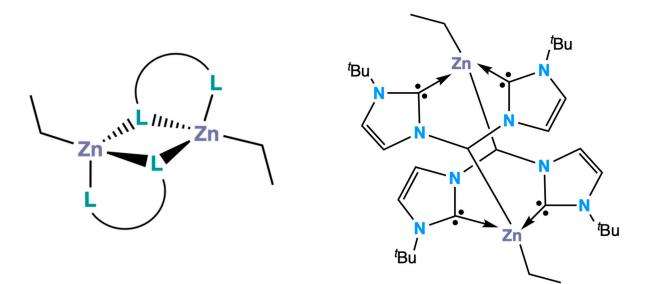


Figure 3. Schematic representation of ethyl zinc complex dimerisation through a [Zn–L]₂ ring; L represents a donor atom of a bidentate ligand (**left**). Bis(*N*-heterocyclic carbene) zinc ethyl complex reported by Rit et al. exhibiting similar dimerisation to **1** and **2** (**right**).

In both 1 and 2 (Figure 2), two coordination sites around Zn1 are occupied by the coordination of the appropriate bidentate ligand L^1/L^2 which bonds through the O1' and N1' atoms, and the bonding of L^1/L^2 forms a puckered six-membered ZnOC₃N ring. Zn1 forms a dative interaction with C3 on the symmetry equivalent monomer unit, and as such, 1 and 2 exist as dimers in the solid state with two dative interactions between two monomer units, in which Zn1 adopts a highly distorted tetrahedral geometry. Taking compound 1 as an example, the longest interaction made by Zn1 is the Zn1–C3 interaction between Zn1 on one monomer unit to C3 on the other (2.408(3) Å). The Zn1-C10 bond measures 1.980(3) Å, which is typical of a Zn–C bond. The increased value of the Zn1– C3 distance is highly indicative of a dative interaction between Zn1 and C3. Zn1 also bonds to O1' and N1' of the ligand L^1 , with bond lengths of 2.046(2) Å and 2.013(2) Å, respectively (Table 1). The largest bond angle about the Zn atom in 1 is $138.12(13)^{\circ}$ for N1'–Zn1–C10, which is over 40° larger than the N1'–Zn1–O1' angle (93.15(9)°). The large N1'–Zn1–C10 bond angle reduces the steric interaction between the terminal ethyl group on Zn1 and the ⁱPr group on N1'. However, the O1'–Zn1–N1' angle is small due to the steric constraints of the formed ring system. The other angles about Zn1 of O1'-Zn1-C3, O1'-Zn1-C10, N1'-Zn1-C3 and C3-Zn1-C10 have intermediate bond angles of 97.02(9)°, 114.23(11)°, $98.26(9)^{\circ}$ and $108.42(12)^{\circ}$, respectively. The deviations from the ideal tetrahedral angle of 109.5° are expected in complexes of this type and result from the inflexibility of the bound chelate ligand and the requirement to reduce the steric interaction between the ¹Pr groups and terminal ethyl groups. The trends for bond angles and lengths are analogous for 2 due to both complexes having very similar structures in the solid state.

Bond Lengths/Å	1	2	3
Zn1-O1	2.046(2)	2.0278(14)	2.0233(10)
Zn1-O2	-	-	2.1329(10)
Zn1-N1	2.013(2)	1.9964(18)	2.0262(11)
Zn1-CH ₂ CH ₃	1.980(3)	1.962(2)	1.9806(14)
O1-C	1.252(4)	1.254(3)	1.3141(17)
Bond Angles/°			
01-Zn1-N1	93.15(9)	92.99(7)	83.47(4)
O1-Zn1-CH ₂ CH ₃	114.23(11)	121.22(9)	123.96(5)
N1-Zn1-CH ₂ CH ₃	138.12(13)	133.75(10)	130.03(5)

Table 1. Selected bond lengths (Å) and bond angles (°) for compounds 1, 2 and 3.

The bond angles around the four coordinate Zn centres in 1 and 2 both have a range that deviates significantly from the 109.5° that would be observed for a centre with perfect tetrahedral geometry. This is due to the inflexibility of the chelating ligand and the relatively small bite angle resulting from the (OC(OEt)CHC(Me)N(R)) chain, where R is 'Pr in 1 and $(CH_2)_2$ ^{*i*}Pr in **2**. The N1–Zn1–CH₂CH₃ bond angle is the largest in both complexes as to reduce the steric conflict in the complexes and place distance between the organic ligand on the N atom and the ethyl group on the Zn atom. The N1'–Zn1–C10 angle in 1 measures $138.12(13)^\circ$, compared to the N1–Zn1–C12 bond angle of $133.75(10)^\circ$ in **2**. The ^{*i*}Pr group on the N in 1 has a short carbonyl chain and less rotation available about its bonds. This results in the steric bulk of the ligand being in closer proximity to the ethyl group on the Zn, requiring an increased bond angle between them. However, the isopentyl group has a longer carbonyl chain with increased rotation available, which causes a reduction in the steric frustration with the ethyl group on the Zn allowing for a smaller bond angle. This is compensated for by the angle between the O, Zn and C on the ethyl group, which measures 114.23(11)° for the O1'–Zn1–C10 bond angle in 1 and 121.22(9)° for the O1–Zn1–C12 bond angle in 2.

The Zn centre in both 1 and 2 retains one ethyl group from the diethylzinc while forming two bonds to form a puckered $ZnOC_3N$ ring from the β -aminoenoate ligand and one dative bond to the second monomer unit. Delocalisation in the rings in both complexes

is evidenced by the shorter length of the C–O, C–N and C–C bonds within the formed rings when compared to those outside of it. Most bond lengths are slightly shorter in **2**, for example the Zn1–O1 and Zn1–N1 bonds measure 2.0278(14) Å and 1.9964(18) Å, respectively, which compares to 2.046(2) and 2.013(2) Å for the Zn1–O1' and Zn1–N1' bonds, respectively, in **1**. However, **2** does have a slightly longer dative bond between the two monomer units, with the Zn1–C3' measuring 2.452(2) Å compared to the equivalent Zn1–C3 bond measuring 2.408(3) Å in **1**.

The structural parameter τ_4' was used to quantify the degree of distortion at the zinc centre. The zinc centres in **1** and **2** adopted highly distorted tetrahedral geometries with τ_4' values of 0.69 and 0.71, respectively. It can be argued that the further the τ_4' value deviates from the ideal value of 0 (square planar) or 1 (tetrahedral), the more unstable the molecule will be and the more likely it will be that it decomposes at a lower temperature, making it a better contender as a precursor. However, deposition is also dependent on the similarity between the molecular geometry of the precursor and the arrangement of atoms in the desired bulk material, in which case it would be favourable to have a τ_4' value closer to ideal values. This is especially true for zinc oxide, where it has been shown that certain geometries of precursors lead to films with certain preferred orientations [26,27]. For zinc oxide, which exists most commonly in the wurtzitic form where both zinc and oxygen atoms adopt tetrahedral geometries, it could be favourable to have precursors with values closer to 1, so as to match the geometries of the precursor to the bulk material.

Similarly to **1** and **2**, peaks observed in the ¹H NMR spectrum of **3** were shifted as compared to the free ligand, indicating that the ligand was coordinated to the zinc centre. The protons corresponding to the bound ethyl group appeared as broad signals, similarly to **1** and **2**. Compound **3** crystallised out of a concentrated toluene solution as a dimeric species in the tetragonal space group $P4_2/n$, with two crystallographically non-equivalent zinc centres (Figure 4). This dimerisation is much more common in zinc complexes, as discussed above. The structural parameter τ_4' for **3** was calculated to be 0.73, indicating a highly distorted tetrahedral zinc centre. Each zinc centre is bound to two oxygen atoms in a [Zn-O]₂ ring structure. All bond lengths including the Zn-O bond lengths are comparable to those in **1** and **2**, measuring 83.47(4)°, which is further from the ideal internal tetrahedral angle for a six-membered ring (109.5°). However, the τ_4' value for **3** is closer to the ideal tetrahedral geometry of 1 as complexes **1** and **2** have greater than 109.5° bond angles for O1–Zn1–CH₂CH₃ and N1–Zn1–CH₂CH₃, causing the coordination geometry around the zinc centres to be more distorted.

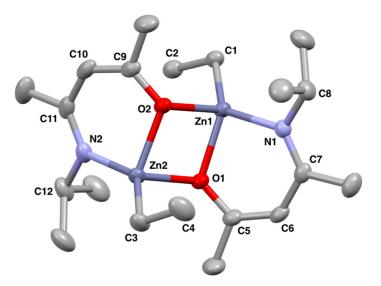


Figure 4. Solid state structure of **3** with thermal ellipsoids drawn at 50% probability and with hydrogen atoms omitted for clarity.

The 1:1 reaction of HL³ with diethylzinc resulted in the formation of **3**, along with the formation of the bis-ligated compound $[Zn(L^3)_2]$, even when conducting a cooled dropwise addition. The ratios of **3** to $[Zn(L^3)_2]$ from ¹H NMR was found to be 2:1 for the 1:1 reaction. Repeats of the reaction with 1.6 eq. and 2.5 eq. excess of diethylzinc still resulted in the formation of $[Zn(L^3)_2]$, with ratios of 3:1 of $3:[Zn(L^3)_2]$, which shows the stability of the bis-ligated complex. The bis-ligated complexes $[Zn(L^1)_2]$ and $[Zn(L^2)_2]$ did not form when conducting these reactions and we believe that this is due to electronic differences in the ligands used. The single-crystal structure of $[Zn(L^3)_2]$ has been reported previously, which shows that the compound is monomeric [28].

In **3**, each Zn atom is bound to two O atoms, which is advantageous for deposition of ZnO as there are more pre-formed Zn–O bonds as required in the bulk material. Even though there is a greater atomic percentage of oxygen in **1** and **2**, each Zn atom is only bound to one oxygen atom. As such, thermal gravimetric analysis (TGA) was used to evaluate the efficacy of **3** as a single source precursor to ZnO. Furthermore, TGA analysis was not able to be carried out on **1** and **2** due to their high moisture and air sensitivity. Due to the inseparable mixture obtained from the reaction of diethylzinc with HL³, the TGA for this 3:1 mixture of **3**:[Zn(L³)₂] was carried out. The thermal profile shows a two-step decomposition pathway, with an onset decomposition temperature of 150 °C, and a relatively wide decomposition window of ~200 °C (Figure 5).

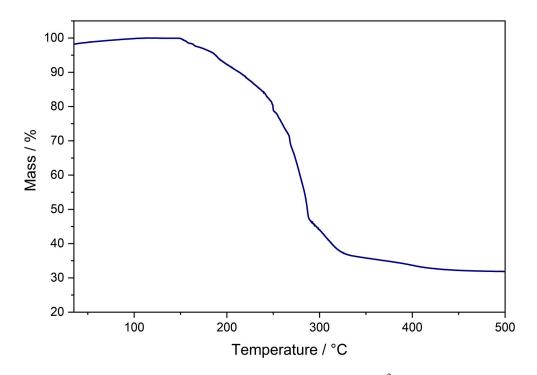


Figure 5. Thermal decomposition profile for the 3:1 mixture of 3:[Zn(L³)₂].

The TGA profile for a similar bis-ligated zinc β -ketoiminate complex, with an ^{*n*}Bu group on the N atom, showed the onset decomposition to be at 250 °C, with complete decomposition at 400 °C [13]. From this, we may hypothesise that the initial decomposition starting at 150 °C is of compound **3**, with the mass loss at the higher temperature of ~300 °C attributed to the decomposition of [Zn(L³)₂]. The same authors also reported the TGA profile for the bis-ligated complex [Zn(L¹)₂], which had an onset decomposition temperature of ~250 °C, with complete decomposition at 400 °C. From the trend seen between **3** and its bis-ligated counterpart, we can infer that **1** and **2** will also have significantly lower decomposition temperatures than their bis-ligated counterparts, perhaps even more so than **3**, as their sensitivity did not allow for TGA analysis to be undertaken. Given that a mixture of 3:1 of **3**:[Zn(L³)₂] was used, it can be calculated that if ZnO was to be formed, a mass% of 32.0% should remain, which is in line with the observed 32.8% final mass% in

the TGA, suggesting that this precursor does decompose to ZnO. This was corroborated by XRD analysis of the thermal decomposition product, which confirmed its identity as ZnO (Figure 6).

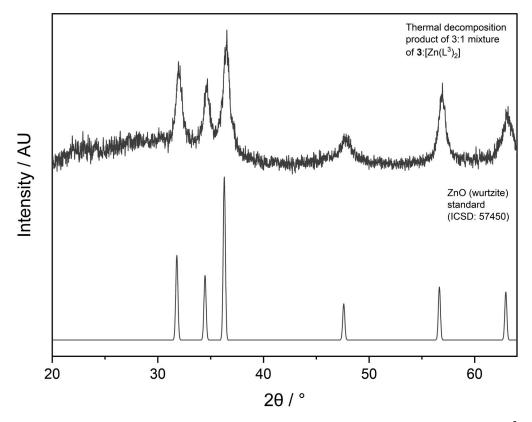


Figure 6. XRD pattern of the thermal decomposition product, ZnO, of the 3:1 mixture of 3:[Zn(L³)₂].

3. Materials and Methods

All preparations were performed under an inert argon atmosphere using standard Schlenk techniques or using an MBraun nitrogen-filled glovebox. All chemicals were obtained from commercial sources. All solvents were obtained from a solvent purification system and stored over molecular sieves. C_6D_6 and $CDCl_3$ were dried using freeze–pump-thaw cycles and stored over molecular sieves. HL^1 and HL^3 were synthesised according to procedures in the literature [14,16].

Single-crystal X-ray diffraction (XRD) data were collected using a SuperNova Atlas (Dual) diffractometer using Cu K α radiation of wavelength 1.54184 Å. Suitable crystals were selected and mounted on a nylon loop and the crystal was kept at 150 K during data collection. Nuclear magnetic resonance (NMR) data were recorded in C₆D₆ solutions using a Bruker Advance III 500 MHz instrument at ambient temperature. ¹H and ¹³C{¹H} NMR assignments were confirmed by ¹H–¹H (COSY and NOESY) and ¹H–¹³C (HSQC and HMBC) experiments where necessary. Thermogravimetric analysis (TGA) measurements were made using a PerkinElmer STA6000 TGA instrument, with a sensitivity of 0.1 mg and using N₂ as the shield gas. The samples were heated from 30 °C to 500 °C, at a heating rate of 10 °C min⁻¹ under the flow of shield gas. XRD patterns were recorded using a Bruker D8 Discover diffractometer.

3.1. Synthesis of OC(OEt)CHC(Me)NH(CH₂)₂ⁱPr (HL²)

Isopentylamine (6.96 cm³, 60 mmol) was added dropwise to ethyl acetoacetate (3.97 cm³, 30 mmol) dispersed over K-10 montmorillonite clay (20 g) in a 3-necked round-bottom flask fitted with an overhead mechanical stirrer. The reaction slurry initially gave out heat and was stirred at room temperature for 15 h. The product was extracted by washing with

3.2. Synthesis of $[(Zn(OC(OEt)CHC(Me)N^{i}Pr)(Et))_{2}] [L^{1}ZnEt]_{2}$ (1)

A solution of HL¹ (1.00 g, 5.84 mmol) in toluene (15 cm³) was added dropwise to a cooled solution of diethylzinc (1.1 M in toluene) (5.26 cm³, 5.84 mmol) in toluene (15 cm³). The resulting solution was brought to room temperature and stirred for 24 h. Toluene was partially removed in vacuo and the remaining solution was left at -18 °C for 48 h. The product crystallised out as yellow tinted crystals suitable for analysis via single-crystal XRD (yield: 1.17 g, 75%). ¹H NMR δ /ppm (C₆D₆, 500 MHz): 0.32 (4H, br, Zn–CH₂CH₃), 0.93 (12 H, d, *J* = 6.4 Hz, (CH₃)₂CH), 1.09 (6H, t, *J* = 7.1 Hz, OCH₂CH₃), 1.28 (6H, br, Zn–CH₂CH₃), 1.61 (6H, s, CH₃C), 3.44 (2H, m, (CH₃)₂CH), 4.03 (4H, q, *J* = 7.1 Hz, OCH₂CH₃), 4.57 (2H, s, CHCO). ¹³C{¹H} NMR δ /ppm (C₆D₆, 500 MHz): 4.8 (Zn–CH₂CH₃), 11.2 (Zn–CH₂CH₃), 14.9 (OCH₂CH₃), 22.2 (CH₃C), 25.6 ((CH₃)₂CH), 49.4 ((CH₃)₂CH), 59.5 (OCH₂CH₃), 79.6 (CHCO), 170.3 (q) (CN), 172.2 (q) (CO). MS: *m*/z [M]⁺⁻: 530.25.

58.3 (CH₃CH₂O), 81.8 (CHCO), 162.1 (q) (CNH), 170.8 (q) (CO). MS: *m*/*z* [M + H]+: 200.11.

3.3. Synthesis of $[(Zn(OC(OEt)CHC(Me)N(CH_2)_2^i Pr)(Et))_2] [L^2ZnEt]_2$ (2)

A solution of HL² (1.00 g, 5.02 mmol) in toluene (15 cm³) was added dropwise to a cooled solution of diethylzinc (1.1 M in toluene) (4.52 cm³, 5.02 mmol) in toluene (15 cm³). The resulting solution was brought to room temperature and stirred for 42 h. Toluene was partially removed in vacuo and the remaining solution was left at -18 °C for 48 h. The product crystallised out as yellow tinted crystals suitable for analysis via single-crystal XRD (yield: 0.98 g, 67%). ¹H NMR δ /ppm (C₆D₆, 500 MHz): 0.21 (4H, q (br), *J* = 8.1 Hz, Zn-CH₂CH₃), 0.81 (12H, d, *J* = 6.6 Hz, (CH₃)₂CH), 1.09 (6H, t, *J* = 7.1 Hz, OCH₂CH₃), 1.20 (6H, t (br), *J* = 8.1 Hz, Zn-CH₂CH₃), 1.25 (4H, m, NCH₂CH₂), 1.41 (4H, m, NCH₂CH₂), 1.61 (6H, s, CH₃C), 2.98 (2H, m, (CH₃)₂CH), 4.04 (4H, q, *J* = 7.1 Hz, OCH₂CH₃), 4.62 (2H, s, CHCO). ¹³C{¹H} NMR δ /ppm (C₆D₆, 500 MHz): 5.7 (Zn-CH₂CH₃), 10.8 (Zn-CH₂CH₃), 14.9 (OCH₂CH₃), 21.8 (CH₃C), 22.8 ((CH₃)₂CH), 26.6 (NCH₂CH₂), 41.9 (NCH₂CH₂), 49.2 ((CH₃)₂CH), 59.6 (OCH₂CH₃), 79.6 (CHCO), 172.6 (q) (CN), 172.7 (q) (CO).

3.4. Synthesis of $[(Zn(OC(Me)CHC(Me)N^iPr)(Et))_2] [L^3ZnEt]_2$ (3)

A solution of HL³ (0.84 g, 6.0 mmol) in toluene (15 cm³) was added dropwise to a cooled solution of diethylzinc (1.1 M in toluene) (5.40 cm³, 6.0 mmol) in toluene (15 cm³). The resulting solution was brought to room temperature and stirred overnight. Toluene was partially removed in vacuo and the remaining solution was left at -18 °C for 24 h after which clear crystals suitable for analysis via single-crystal XRD had formed. ¹H NMR δ /ppm (C₆D₆, 500 MHz): 0.67 (2H, br, Zn–CH₂CH₃), 0.93 (6H, d, *J* = 6.3 Hz, NCH(CH₃)₂), 1.49 (3H, s, NCCH₃), 1.56 (3H, br, Zn–CH₂CH₃), 2.01 (3H, s, OCCH₃), 3.38 (1H, hept, *J* = 6.3 Hz, NCH(CH₃)₂), 4.78 (1H, s, NCCH). ¹³C{¹H} NMR δ /ppm (C₆D₆, 500 MHz): 1.9 (Zn–CH₂CH₃), 21.6 (NC(CH₃)), 24.6 (NCH(CH₃)₂), 27.5 (OC(CH₃)), 50.4 (NCH), 98.8 (NCCH), 169.6 (CN), 179.9 (CO).

4. Conclusions

We have presented the synthesis of three ethyl zinc complexes as potential SSPs for ZnO thin films. The unusual dimerisation of **1** and **2** led to highly unstable complexes, whilst the more common dimerisation seen in **3** offered greater stability and was therefore the most suitable complex for use as a precursor. As such, TGA was carried out on **3** and its decomposition temperature was significantly lower (~250 °C) than its bis-ligated counterpart [Zn(L³)₂], and this relatively low temperature makes **3** suitable for use as an

SSP in CVD processes. Although this reaction yielded a mixture, CVD is usually an in situ process and as such complexes are not isolated. Because the bis-ligated compound $[Zn(L^3)_2]$ is an SSP to ZnO in its own right, we do not believe that the inclusion of a small amount of this would hinder the growth of ZnO when undertaking the deposition of **3** to form ZnO.

The usage of chelating β -amidoenoate and β -ketoiminate ligands along with one ethyl group remaining from the diethylzinc has given rise to a set of heteroleptic complexes with properties intermediate to diethylzinc and bis-ligated zinc β -amidoenoates and β -ketoiminates. They are not pyrophoric due to the chelate ligand, but they are still highly sensitive to air and moisture due to the remaining ethyl group, and are therefore promising as SSPs for ZnO, as evidenced by the TGA data of **3** and its thermal decomposition product confirmed as ZnO by XRD analysis.

Author Contributions: M.A.B. and J.A.M. carried out the experimental work, supervision C.E.K. and C.J.C. All authors have read and agreed to the published version of the manuscript.

Funding: This research was funded by the Engineering and Physical Sciences Research Council (EP-SRC), grant EP/R513143/1 (M.A.B.) and grant EP/G036675 (J.A.M.), and the grants EP/K001515 and EP/L017709.

Institutional Review Board Statement: Not applicable.

Informed Consent Statement: Not applicable.

Data Availability Statement: The data presented in this study are available on request from the corresponding author.

Conflicts of Interest: The authors declare no conflict of interest.

Sample Availability: Samples of the compounds are not available from the authors.

References

- Powell, M.J.; Carmalt, C.J. Aerosols: A Sustainable Route to Functional Materials. *Chem. Eur. J.* 2017, 23, 15543–15552. [CrossRef] [PubMed]
- Pasquarelli, R.M.; Ginley, D.S.; O'Hayre, R. Solution processing of transparent conductors: From flask to film. *Chem. Soc. Rev.* 2011, 40, 5406. [CrossRef]
- 3. Bayram, O.; Sener, E.; İgman, E.; Simsek, O. Investigation of structural, morphological and optical properties of Nickel-doped Zinc oxide thin films fabricated by co-sputtering. *J. Mater. Sci. Mater. Electron.* **2019**, *30*, 3452–3458. [CrossRef]
- 4. Bodea, M.A.; Sbarcea, G.; Naik, G.V.; Boltasseva, A.; Klar, T.A.; Pedarnig, J.D. Negative permittivity of ZnO thin films prepared from aluminum and gallium doped ceramics via pulsed-laser deposition. *Appl. Phys. A* 2013, *110*, 929–934. [CrossRef]
- Bukke, R.N.; Saha, J.K.; Mude, N.N.; Kim, Y.; Lee, S.; Jang, J. Lanthanum Doping in Zinc Oxide for Highly Reliable Thin-Film Transistors on Flexible Substrates by Spray Pyrolysis. ACS Appl. Mater. Interfaces 2020, 12, 35164–35174. [CrossRef] [PubMed]
- Bhachu, D.S.; Sankar, G.; Parkin, I.P. Aerosol Assisted Chemical Vapor Deposition of Transparent Conductive Zinc Oxide Films. *Chem. Mater.* 2012, 24, 4704–4710. [CrossRef]
- 7. SPonja, D.; Sathasivam, S.; Parkin, I.P.; Carmalt, C.J. Highly conductive and transparent gallium doped zinc oxide thin films via chemical vapor deposition. *Sci. Rep.* **2020**, *10*, 638. [CrossRef]
- 8. Nishino, J.; Ohshio, S.; Kamata, K. Preparation of Aluminum-Doped Zinc Oxide Films by a Normal-Pressure CVD Method. *J. Am. Ceram. Soc.* **1992**, *75*, 3469–3472. [CrossRef]
- 9. Hu, J.; Gordon, R.G. Atmospheric pressure chemical vapor deposition of gallium doped zinc oxide thin films from diethyl zinc, water, and triethyl gallium. *J. Appl. Phys.* **1992**, *72*, 5381–5392. [CrossRef]
- 10. Ponja, S.D.; Sathasivam, S.; Parkin, I.P.; Carmalt, C.J. Transparent conductive aluminium and fluorine co-doped zinc oxide films via aerosol assisted chemical vapour deposition. *RSC Adv.* **2014**, *4*, 49723–49728. [CrossRef]
- 11. O'Brien, S.; Nolan, M.G.; Çopuroglu, M.; Hamilton, J.A.; Povey, I.; Pereira, L.; Martins, R.; Fortunato, E.; Pemble, M. Zinc oxide thin films: Characterization and potential applications. *Thin. Solid Films* **2010**, *518*, 4515–4519. [CrossRef]
- Potter, D.B.; Bhachu, D.S.; Powell, M.J.; Darr, J.A.; Parkin, I.P.; Carmalt, C.J. Al-, Ga-, and In-doped ZnO thin films via aerosol assisted CVD for use as transparent conducting oxides: Al-, Ga-, and In-doped ZnO thin films via aerosol assisted CVD. *Phys. Status Solidi. A* 2016, 213, 1346–1352. [CrossRef]
- 13. Matthews, J.S.; Onakoya, O.O.; Ouattara, T.S.; Butcher, R.J. Synthesis and characterization of zinc AP-MOCVD precursors and their utility in the growth of ZnO. *Dalton. Trans.* **2006**, 3806. [CrossRef]
- 14. Knapp, C.E.; Dyer, C.; Chadwick, N.P.; Hazael, R.; Carmalt, C.J. Metal β-diketoiminate precursor use in aerosol assisted chemical vapour deposition of gallium- and aluminium-doped zinc oxide. *Polyhedron* **2018**, *140*, 35–41. [CrossRef]

- Cosham, S.D.; Johnson, A.L.; Hamilton, J.A.; Hill, M.S.; Molloy, K.C.; Castaing, R.; Kociok-Köhn, G. Synthesis and Characterization of Fluorinated β-Ketoiminate Zinc Precursors and Their Utility in the AP-MOCVD Growth of ZnO:F: Fluorinated β-Ketoiminate Zinc Precursors. *Eur. J. Inorg. Chem.* 2015, 2015, 4362–4372. [CrossRef]
- Manzi, J.A.; Knapp, C.E.; Parkin, I.P.; Carmalt, C.J. Aerosol-Assisted Chemical-Vapour Deposition of Zinc Oxide from Single-Source β-Iminoesterate Precursors: Aerosol-Assisted Chemical Vapour Deposition of Zinc Oxide. *Eur. J. Inorg. Chem.* 2015, 2015, 3658–3665. [CrossRef]
- 17. Manzi, J.A.; Knapp, C.E.; Parkin, I.P.; Carmalt, C.J. Synthesis of Trimeric Organozinc Compounds and their Subsequent Reaction with Oxygen. *Chem. Open* **2016**, *5*, 301–305. [CrossRef]
- 18. Auld, J.; Houlton, D.J.; Jones, A.C.; Rushworth, S.A.; Malik, M.A.; O'Brien, P.; Critchlow, G.W. Growth of ZnO by MOCVD using alkylzinc alkoxides as single-source precursors. *J. Mater. Chem.* **1994**, *4*, 1249. [CrossRef]
- 19. Bekermann, D.; Ludwig, A.; Toader, T.; Maccato, C.; Barreca, D.; Gasparotto, A.; Bock, C.; Wieck, A.D.; Kunze, U.; Eugenio, T.; et al. MOCVD of ZnO Films from Bis(Ketoiminato)Zn(II) Precursors: Structure, Morphology and Optical Properties. *Chem. Vap. Depos.* **2011**, *17*, 155–161. [CrossRef]
- 20. Bhide, M.A.; Mears, K.L.; Carmalt, C.J.; Knapp, C.E. Synthesis, solution dynamics and chemical vapour deposition of heteroleptic zinc complexes via ethyl and amide zinc thioureides. *Chem. Sci.* **2021**. [CrossRef]
- 21. Hursthouse, M.B.; Malik, M.A.; Motevalli, M.; O'Brien, P. Mixed alkyl dialkylthiocarbamates of zinc and cadmium: Potential precursors for II/VI materials. X-ray crystal structure of [MeZnS2CNEt2]2. *Organometallics* **1991**, *10*, 730–732. [CrossRef]
- 22. di Iulio, C.; Middleton, M.; Kociok-Köhn, G.; Jones, M.D.; Johnson, A.L. Synthesis and Characterization of Zinc Ketoiminate and Zinc Alkoxide-/Phenoxide-Ketoiminate Complexes. *Eur. J. Inorg. Chem.* **2013**, 2013, 1541–1554. [CrossRef]
- Sullivan, H.S.I.; Parish, J.D.; Thongchai, P.; Kociok-Köhn, G.; Hill, M.S.; Johnson, A.L. Aerosol-Assisted Chemical Vapor Deposition of ZnS from Thioureide Single Source Precursors. *Inorg. Chem.* 2019, 58, 2784–2797. [CrossRef]
- Sen, T.K.; Mukherjee, A.; Modak, A.; Mandal, S.K.; Koley, D. Substitution effect on phenalenyl backbone in the rate of organozinc catalyzed ROP of cyclic esters. *Dalton. Trans.* 2013, 42, 1893–1904. [CrossRef]
- 25. Rit, A.; Spaniol, T.P.; Okuda, J. Dinuclear Zinc Hydride Supported by an Anionic Bis(N-Heterocyclic Carbene) Ligand. *Chem. Asian J.* **2014**, *9*, 612–619. [CrossRef]
- 26. Fujimura, N.; Nishihara, T.; Goto, S.; Xu, J.; Ito, T. Control of preferred orientation for ZnOx films: Control of self-texture. *J. Cryst. Growth* **1993**, 130, 269–279. [CrossRef]
- 27. Barron, A.; Hepp, A.; Apblett, A. (Eds.) *Nanomaterials via Single-Source Precursors: Synthesis, Processing and Applications,* 1st ed.; ELSEVIER: Amsterdam, The Netherlands, 2021.
- Granum, D.M.; Paul, J.R.; Joshua, A.C.; Thomas, K.M.; Chelsea, M.W.; Anastasia, K.B.; Navamoney, A.; Brad, S.P.; Mark, P.M. Synthesis and Characterisation of Sterically Encumbered b-ketoiminate Complexes of Iron(II) and Zinc(II). *Dalton. Trans.* 2011, 40, 5881–5890. [CrossRef]